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Correction: Direct synthesis of large-scale hierarchical MoS₂ films nanostructured with orthogonally oriented vertically and horizontally aligned layers

Xiaoyan Zhang,^a Saifeng Zhang,^a Bohua Chen,^b Hao Wang,^b Kan Wu,^b Yang Chen,^c Jintai Fan,^a Shen Qi,^a Xiaoli Cui,^c Long Zhang^a and Jun Wang^{*a,d}

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Correction for 'Direct synthesis of large-scale hierarchical MoS₂ films nanostructured with orthogonally oriented vertically and horizontally aligned layers' by Xiaoyan Zhang *et al.*, *Nanoscale*, 2016, DOI: 10.1039/c5nr05938k.

The authors would like to make an amendment to line 58 (right column) on page 4 of their article. The term “(5.7 for 6 h, and 5.4 for 8 h)” should read “(0.57 for 6 h, and 0.54 for 8 h)”.

The authors also wish to correct the term “(NH₂)₂S” to “(NH₂)₂CS” in the sentence beginning “Here, (NH₄)₂MoO₄ and...” in line 12 on page 3 and in Fig. 1 of the original paper.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

^aKey Laboratory of Materials for High-Power Laser, Shanghai Institute of Optics and Fine Mechanics (SIOM), Chinese Academy of Sciences (CAS), Shanghai 201800, China.
E-mail: jwang@siom.ac.cn

^bState Key Laboratory of Advanced Optical Communication Systems and Networks, Department of Electronic Engineering, Shanghai Jiao Tong University, Shanghai 200240, China

^cDepartment of Materials Science, Fudan University, Shanghai 200433, China

^dState Key Laboratory of High Field Laser Physics, Shanghai Institute of Optics and Fine Mechanics, Chinese Academy of Sciences, Shanghai 201800, China